

CD4086B Types

CMOS Expandable 4-Wide 2-Input AND-OR-INVERT Gate

High-Voltage Types (20-Volt Rating)

CD4086B contains one 4-wide 2-input AND-OR-INVERT gate with an INHIBIT/EXP input and an ENABLE/EXP input. For a 4-wide A-O-I function INHIBIT/EXP is tied to V_{SS} and ENABLE/EXP to V_{DD}. See Fig.10 and its associated explanation for applications where a capability greater than 4-wide is required.

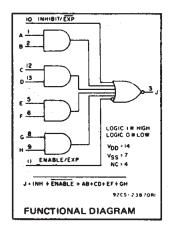
The CD4086B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

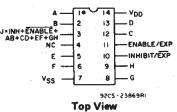
Features:

- Medium-speed operation tpHL = 90 ns; tpLH = 140 ns (typ.) at 10 V
- INHIBIT and ENABLE inputs
- Buffered outputs
- 100% tested for quiescent current at 20 V
- Maximum input leakage current of 18 V over full package-temperature range;
 100 nA at 18 V and 25°C
- Noise margin (over full package termperature range):

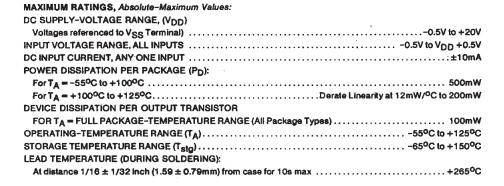
1 V at V_{DD} = 5 V 2 V at V_{DD} = 10 V 2.5 V at V_{DD} = 15 V

- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"





TERMINAL ASSIGNMENT



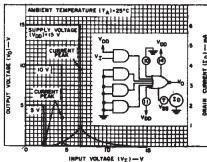


Fig. 1 — Typical voltage and current transfer characteristics.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

	LIM		
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For T _A = Full Package- Temperature Range)	3	18	٧

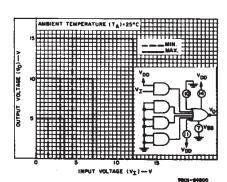


Fig. 2 — Minimum and maximum voltage transfer characteristics,

STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC		DITIO	NS	LIMITS AT INDICATED TEMPERATURES (°C)					ICATED TEMPERATURES (°C) UNI		
LEMISTIC	v _o	VIN	V _{DD}						1		
	(V).	(V)	(V)	55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent		0,5	5	1	1	30	30	-	0.02	1	, and the second
Device		0,10	10	2	2	60	60		0.02	2	μА
Current	_	0,15	15	4	4	120	120	_	0.02	4	μA
IDD Max.	_	0,20	20	20	20	600	600	<u> </u>	0.04	20	
Output Low								1 9	: .		1
(Sink)	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	387 a 1	54	
Current,	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1,15	-1.6	-3.2		
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	_	
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_	
Output Volt-											
age:	_	0,5	5		0.0)5		_	0	0.05	
Low-Level,		0,10	10		0.0)5		-	0	0.05	
V _{OL} Max.	.7.	0,15	15		0.0)5	٠.	-	Q	0.05	v
Output Volt-		F . 4. 1									V
age:	_	0,5	5		4.9	95		4.95	5	_	
High-Level,	_	0,10	10		9.9	95		9.95	10	_	
V _{OH} Min.		0,15	15		14.	95		14.95	15	_	
Input Low	0.5,4.5		5		1.	5		_		1.5	
Voltage,	1,9	-	10		3	- L		_	_	3	
VIL Max.	1.5,13.5	-,	15		4				_	4	
Input High	0.5,4.5	_	5	3.5				3.5	_	_	٧
Voltage,	1,9	-	10	7				7	_		
V _{IH} Min.	1.5,13.5	-	15		1	1		11	_		
Input Current, IN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μΑ

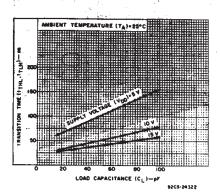


Fig.6 - Typical transition time vs. load capacitance.

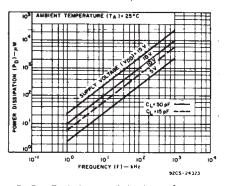


Fig.7 — Typical power dissipation vs. frequency,

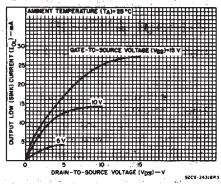


Fig. 3 — Typical output low (sink) current characteristics.

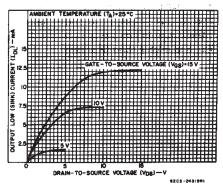


Fig. 4 — Minimum output low (sink) current characteristics.

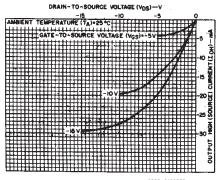


Fig.5 — Typical output high (source) current characteristics.

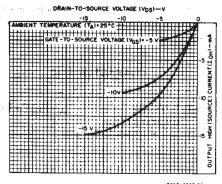
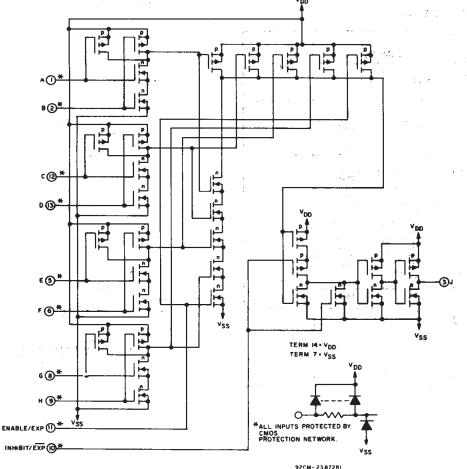


Fig.8 – Minimum output high (source) current characteristics.



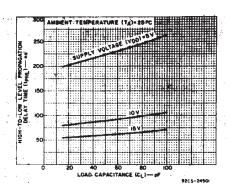


Fig. 11 — Typical DATA or ENABLE high-to-low level propagation delay time vs. load capacitance.

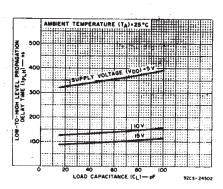
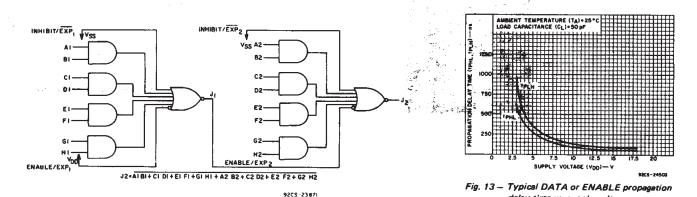


Fig. 12 — Typical DATA or ENABLE low-to-high level propagation delay time vs. load capacitance.

delay time vs. supply voltage.

Fig. 9 - CD4086B schematic diagram.



CD4086B Types

Fig. 10 - Two CD40868's connected as an 8-wide 2-input A-O-I gate.

Fig. 10 above shows two CD4086's utilized to obtain an 8-wide 2-input A-O-I function. The output (J1) of one CD4086 is fed directly to the ENABLE/EXP2 line of the second CD4086. In a similar fashion, any

NAND gate output can be fed directly into the ENABLE/EXP input to obtain a 5-wide A-O-I function. In addition, any AND gate output can be fed directly into the IN-HIBIT/EXP input with the same result.

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CD4086B Types

DYNAMIC ELECTRICAL CHARACTERISTICS

At T_A = 25°C; Input t_r , t_f = 20 ns, C_L = 50 pF, R_L = 200 $k\Omega$

	CONDI	TIONS	LIF		
CHARACTERISTIC		V _{DD} (V)	TYP.	MAX.	UNITS
Propagation Delay Time		5	225	450	
(Data):		10	90	180	ns
High-to-Low Level, tpHL	1	15	60	120	1
		5	310	620	
Low-to-High Level, tpLH		10	125	250	ns
	<u>L</u>	15	90	180	1
Propagation Delay Time		5	150	300	
(Inhibit): High-to-Low		10	60	120	ns
Level, tPHL(INH)		15	40	80	1
Laure de Illah I arah		5	250	500	
Low-to-High Level,		10	100	200	ns
^t PLH(INH)		15	70	140]
Transision Time		5	100	200	
Transition Time,		10	50	100	ns
tthL ^{, t} tLH		15	40	80	1
Input Capacitance CIN	Any Input		5	7.5	pF

TEST CIRCUITS

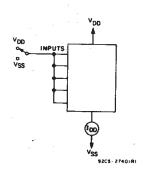


Fig. 14 - Quiescent device current.

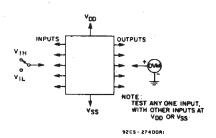
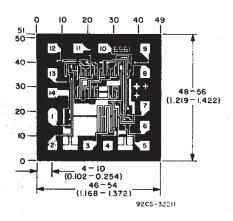


Fig. 15 - Input voltage.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .

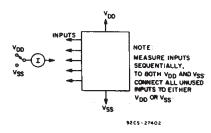


Fig. 16 - Input leakage current.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
CD4086BE	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4086BE
CD4086BE.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4086BE
CD4086BF3A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4086BF3A
CD4086BF3A.A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4086BF3A
CD4086BM	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4086BM
CD4086BM.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4086BM
CD4086BMT	Active	Production	SOIC (D) 14	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4086BM
CD4086BMT.A	Active	Production	SOIC (D) 14	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4086BM

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4086B, CD4086B-MIL:

◆ Catalog : CD4086B

Military : CD4086B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	_	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4086BMT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ı	CD4086BMT	SOIC	D	14	250	213.0	191.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4086BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4086BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4086BE.A	N	PDIP	14	25	506	13.97	11230	4.32
CD4086BE.A	N	PDIP	14	25	506	13.97	11230	4.32
CD4086BM	D	SOIC	14	50	506.6	8	3940	4.32
CD4086BM.A	D	SOIC	14	50	506.6	8	3940	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



NOTES:

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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